

3.5A STEP DOWN SWITCHING REGULATOR

1 Features

- UP TO 3.5A STEP DOWN CONVERTER
- OPERATING INPUT VOLTAGE FROM 8V TO 55V
- 3.3V AND 5.1V ($\pm 1\%$) FIXED OUTPUT, AND ADJUSTABLE OUTPUTS FROM:
0.5V TO 50V (3.3V type)
5.1V TO 50V (5.1 type)
- FREQUENCY ADJUSTABLE UP TO 300KHz
- VOLTAGE FEED FORWARD
- ZERO LOAD CURRENT OPERATION (min 1mA)
- INTERNAL CURRENT LIMITING (PULSE BY PULSE AND HICCUP MODE)
- PRECISE 5.1V (1.5%) REFERENCE VOLTAGE EXTERNALLY AVAILABLE
- INPUT/OUTPUT SYNCHRONIZATION FUNCTION
- INHIBIT FOR ZERO CURRENT CONSUMPTION (100 μ A Typ. at $V_{CC} = 24V$)
- PROTECTION AGAINST FEEDBACK DISCONNECTION
- THERMAL SHUTDOWN
- OUTPUT OVERVOLTAGE PROTECTION
- SOFT START FUNCTION

2 Description

The L4973 is a step down monolithic power switching regulator delivering 3.5A at fixed voltages of 3.3V or 5.1V and using a simple external divider output adjustable voltage up to 50V. Realized in BCD mixed technology, the device uses an internal power D-MOS transistor (with a typical $R_{ds(on)}$ of 0.15ohm) to obtain very high efficiency and very fast switching times.

Figure 1. Packages



Table 1. Order Codes

Part Number	Package
L4973D3.3	SO-20
L4973D3.3-013TR	SO-20 Tape & Reel
L4973D5.1	SO-20
L4973D5.1-013TR	SO-20 Tape & Reel
L4973V3.3	POWERDIP-18
L4973V5.1	POWERDIP-18

Switching frequency up to 300KHz are achievable (the maximum power dissipation of the packages must be observed).

A wide input voltage range between 8V to 55V and output voltages regulated from 3.3V to 40V cover the majority of the today applications.

Features of this new generation of DC-DC converter includes pulse by pulse current limit, hiccup mode for output short circuit protection, voltage feed forward regulation, soft start, input/output synchronization, protection against feedback loop disconnection, inhibit for zero current consumption and thermal shutdown.

Packages available are in plastic dual in line, DIP-18 (12+3+3) for standard assembly, and SO20 (12+4+4) for SMD assembly.

Figure 2. Block Diagram

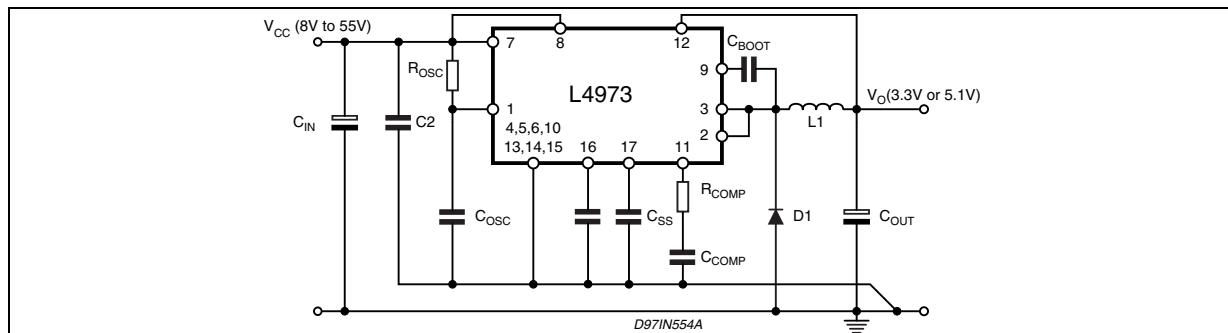


Figure 3. Pin Connections (Top view)

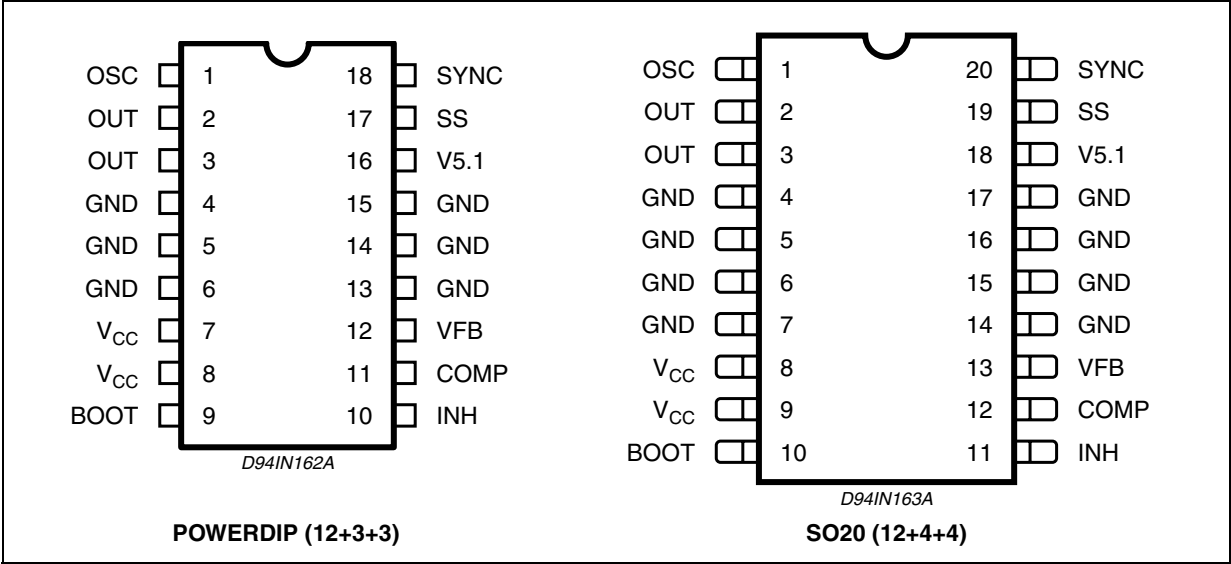


Figure 4. Block Diagram

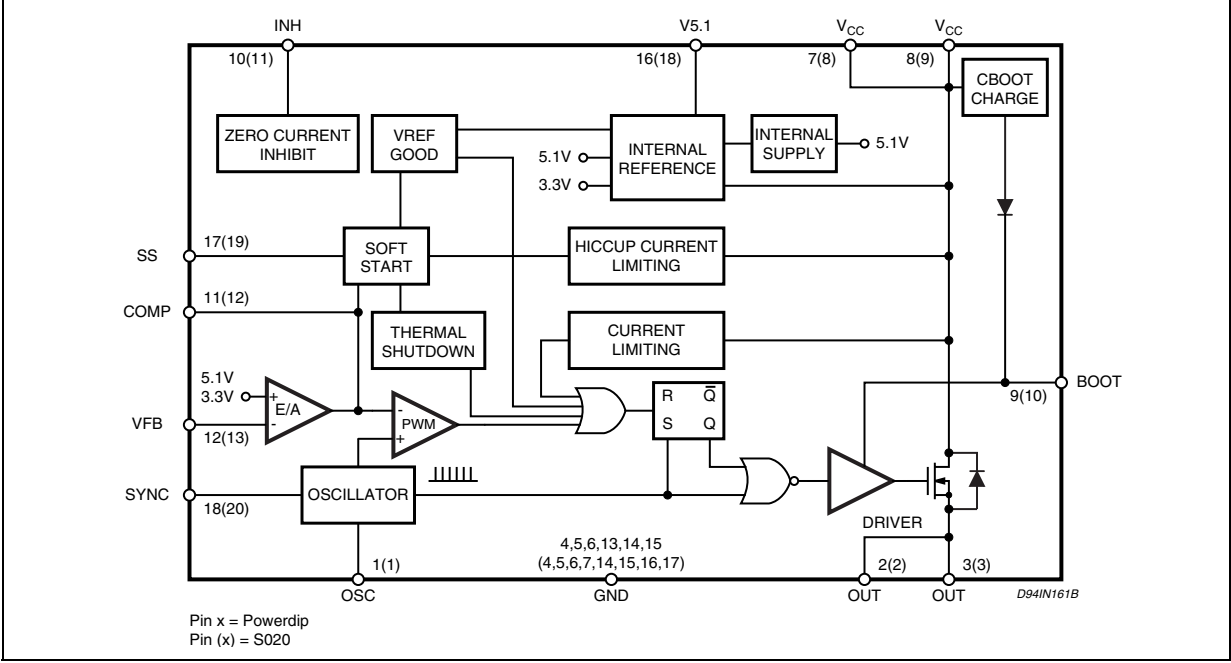


Table 2. Thermal Data

Symbol	Parameter	Value		Unit
R _{th(j-pin)}	Thermal Resistance Junction to pin Max.	12	15	°C/W
R _{th(j-amb)}	Thermal Resistance to Ambient Max.	60 (*)	80 (*)	°C/W

(*) Package mounted on board.

Table 3. Pin Description

N°	Pin		Function
11	12	COMP	E/A output to be used for frequency compensation
10	11	INH	A logic signal (active high) disables the device (sleep mode operation). If not used it must be connected to GND; if floating the device is disabled.
9	10	BOOT	A capacitor connected between this pin and the output allows to drive the internal D-MOS.
18	20	SYNC	Input/Output synchronization.
7,8	8,9	V _{CC}	Unregulated DC input voltage
2,3	2,3	OUT	Stepdown regulator output.
12	13	VFB	Stepdown feedback input. Connecting the output directly to this pin results in an output voltage of 3.3V for the L4973V3.3 and 5.1V. An external resistive divider is required for higher output voltages. For output voltage resistive divider is required for higher output voltages. For output voltage less than 3.3V, see note ** and Figure 32.
16	18	V5.1	Reference voltage externally available.
4,5,6 13,14,15	4,5,6,7 14,15,16 ,17	GND	Signal ground
1	1	OSC	An external resistor connected between the unregulated input voltage and Pin 1 and a capacitor connected from Pin 1 to ground fixes the switching frequency. (Line feed forward is automatically obtained)

Table 4. Absolute Maximum Ratings

Symbol		Parameter	Value	Unit
DIP-18	S0-20			
V ₇ , V ₈	V ₉ , V ₈	Input voltage	58	V
V ₂ , V ₃	V ₂ , V ₃	Output DC voltage Output peak voltage at t = 0.1μs f = 200KHz	-1 - 5	V V
I ₂ , I ₃	I ₂ , I ₃	Maximum output current	int. limit.	
V ₉ -V ₈	V ₁₀ -V ₈		14	V
V ₉	V ₁₀	Bootstrap voltage	70	V
V ₁₁	V ₁₂	Analog input voltage (V _{CC} = 24V)	12	V
V ₁₇	V ₁₉	Analog input voltage (V _{CC} = 24V)	13	V
V ₁₂	V ₁₃	(V _{CC} = 20V)	6 -0.3	V V
V ₁₈	V ₂₀	(V _{CC} = 20V)	5.5 0.3	V V
V ₁₀	V ₁₁	Inhibit	V _{CC} -0.3	V V
P _{tot}		DIP 12+3+3 Power dissipation a T _{pins} ≤ 90°C (T _{amb} = 70°C no copper area) (T _{amb} = 70°C 4cm copper area on PCB)	5 1.3 2	W W W
		SO-20 Power dissipation a T _{pins} = 90°C	4	W
T _J , T _{STG}		Junction and storage temperature	-40 to 150	°C

Table 5. Electrical Characteristics(Refer to the test circuit, $V_{CC} = 24V$; $T_j = 25^\circ C$, $C_{OSC} = 2.7nF$; $R_{OSC} = 20K\Omega$; unless otherwise specified)• = specifications referred to T_j from 0 to $125^\circ C$.

Symbol	Parameter	Test Condition		Min.	Typ.	Max.	Unit
DYNAMIC CHARACTERISTICS							
	Input Voltage Range (*)	$V_O = V_{REF}$ to 40V; $I_O = 3.5A$	•	8		55	V
	Output Voltage L4973V5.1	$I_O = 1A$		5.05	5.1	5.15	V
		$I_O = 0.5A$ to 3.5A $V_{CC} = 8V$ to 55V		5.00	5.1	5.20	V
			•	4.95	5.1	5.25	V
	Output Voltage L4973V3.3	$I_O = 1A$		3.326	3.36	3.393	V
		$I_O = 0.5A$ to 3.5A $V_{CC} = 8V$ to 40V		3.292	3.36	3.427	V
			•	3.26	3.36	3.46	V
	$R_{DS(on)}$	$V_{CC} = 10.5V$ $I_O = 3.5A$			0.15	0.22	W
			•			0.35	W
	Maximum Limiting Current	$V_{CC} = 8V$ to 55V	•	4	4.5	5.5	A
η	Efficiency	$V_O = 5.1V$; $I_O = 3.5A$			90		%
		$V_O = 3.3V$; $I_O = 3.5A$			85		%
	Switching Frequency		•	90	100	110	KHz
	Supply Voltage Ripple Rejection	$V_i = V_{CC} + 2V_{RMS}$ $V_O = V_{ref}$; $I_O = 1A$; $f_{ripple} = 100Hz$		60			dB
Δf_{sw}	Switching Frequency Stability vs, Supply Voltage	$V_{CC} = 8V$ to 55V			2	5	%
REFERENCE SECTION							
	Reference Voltage			5.025	5.1	5.175	V
		$I_{ref} = 0$ to 20mA; $V_{CC} = 8$ to 55V	•	4.950	5.1	5.250	V
	Line Regulation	$I_{ref} = 0mA$; $V_{CC} = 8$ to 55V			5	10	mV
	Load Regulation	$V_{ref} = 0$ to 5mA; $V_{CC} = 0$ to 20mA			2	10	mV
					6	25	mV
	Short Circuit Current			30	65	100	mA
SOFT START							
	Soft Start Charge Current			30	45	60	μA
	Soft Start Discharge Current			15	22	30	μA
INHIBIT							
	High Level Voltage		•	3.0			V
	Low Level Voltage		•			0.8	V
	I_{source} High Level	$V_{INH} = 3V$	•	10	16	50	μA
	I_{source} Low Level	$V_{INH} = 0.8V$	•	10	15	50	μA
DC CHARACTERISTICS							
	Total Operating Quiescent Current	Duty Cycle = 50%			4	6	mA
	Quiescent Current	Duty Cycle = 0			2.7	4	mA
	Total stand-by quiescent current	$V_{CC} = 24V$; $V_{INH} = 5V$			100	200	μA
		$V_{CC} = 55V$; $V_{INH} = 5V$			150	300	μA

Table 5. Electrical Characteristics (continued)(Refer to the test circuit, $V_{CC} = 24V$; $T_j = 25^\circ C$, $C_{OSC} = 2.7nF$; $R_{OSC} = 20K\Omega$; unless otherwise specified)• = specifications referred to T_j from 0 to $125^\circ C$.

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
ERROR AMPLIFIER						
	High Level Output Voltage		11.0			V
	Low Level Output Voltage				0.65	V
	Source Bias Current		1	2	3	μA
	Source Output Current		200	300	600	μA
	Sink Output Current		200	300		μA
	Supply Voltage Ripple Rejection	$V_{COMP} = V_{FB}$ $C_{REF} = 4.7mF$ 1-5mA load current	60	80		dB
	DC Open Loop Gain	$R_L = \infty$	50	60		dB
	Transconductance	$I_{comp} = -0.1$ to $0.1mA$; $V_{comp} = 6V$		2.5		mS
OSCILLATOR SECTION						
	Ramp valley		0.78	0.85	0.92	V
	Ramp peak	$V_{CC} = 8V$ $V_{CC} = 55V$	1.9 9	2.1 9.6	2.3 10.2	V V
	Maximum Duty Cycle		95	97		%
	Maximum Frequency	Duty Cycle = 0%; $R_{OSC} = 13K\Omega$; $C_{OSC} = 820pF$;			300	KHz
SYNC FUNCTION						
	High Input Voltage	$V_{CC} = 8V$ to $55V$	3.5			V
	Low Input Voltage	$V_{CC} = 8V$ to $55V$			0.9	V
	Slave Sink Current		0.15	0.25	0.45	mA
	Master Output Amplitude	$I_{source} = 3mA$	4	4.5		V
	Output Pulse Width	no load, $V_{sync} = 4.5V$	0.20	0.35		μs

(*) Pulse testing with a low duty cycle.

(**) The maximum power dissipation of the package must be observed.

Figure 7. Evaluation Board (Solder Side)

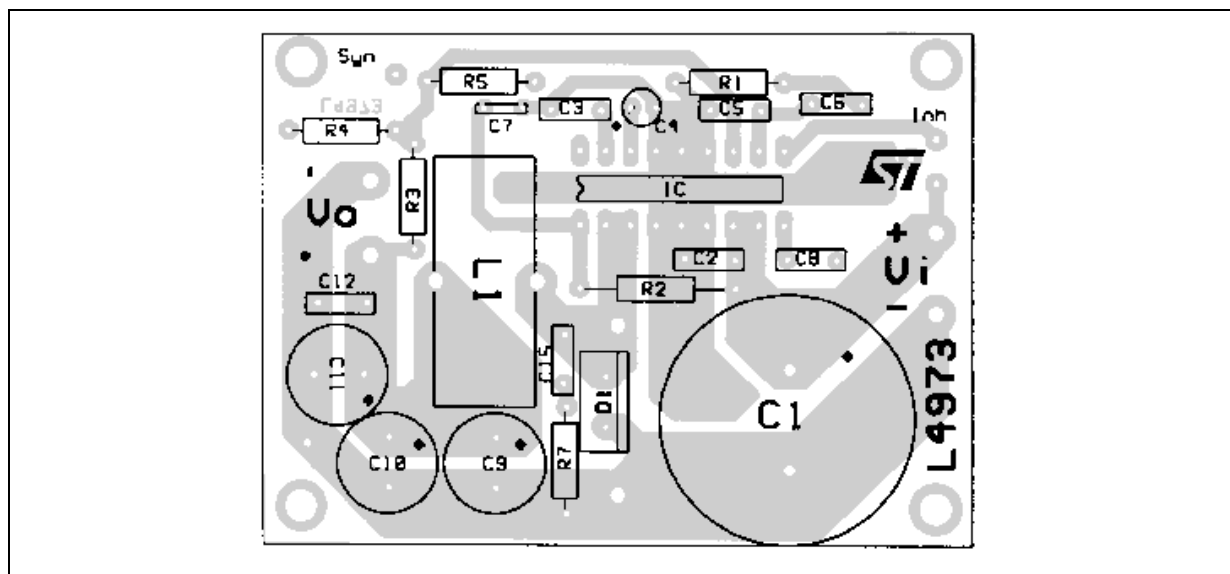


Figure 8. Application Circuit (see fig. 5 part list)

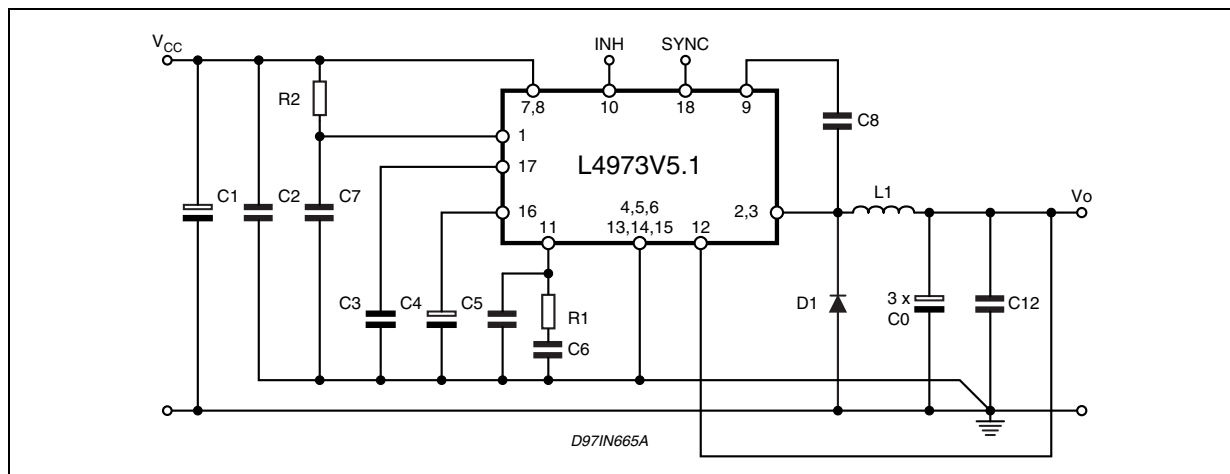


Figure 9. Application Circuit (see fig. 5 part list)

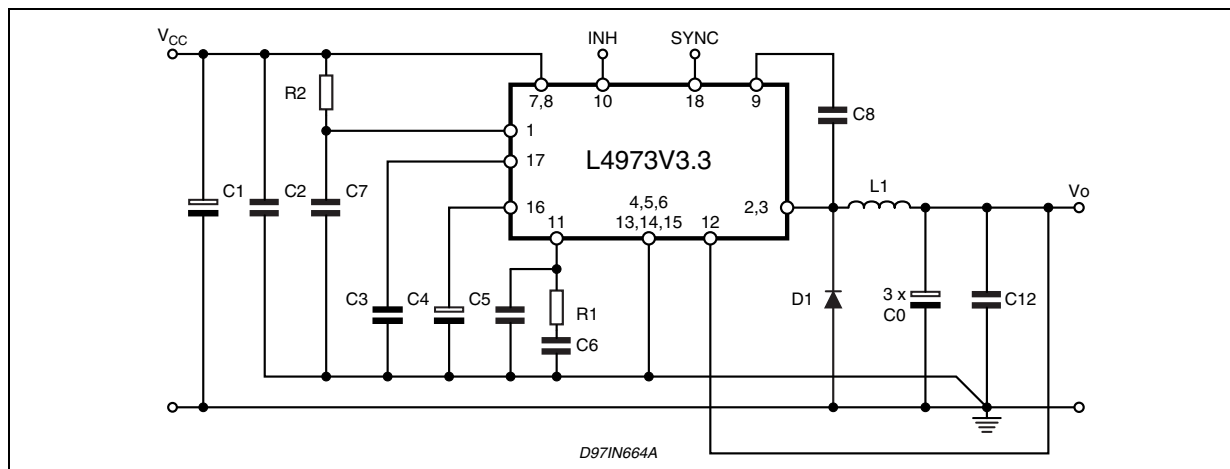


Figure 10. Quiescent Drain Current vs. Input Voltage (0% Duty Cycle)

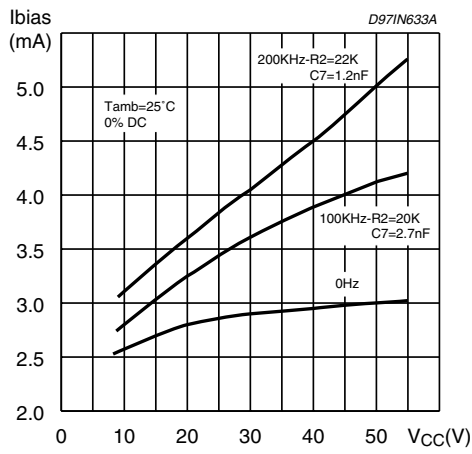


Figure 11. Quiescent Drain Current vs. Junction Temperature

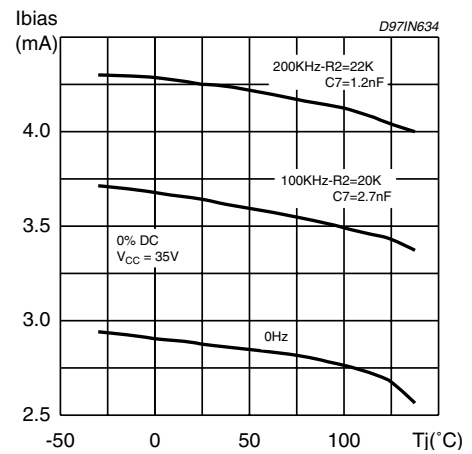


Figure 12. Stand by Drain Current vs. input Voltage

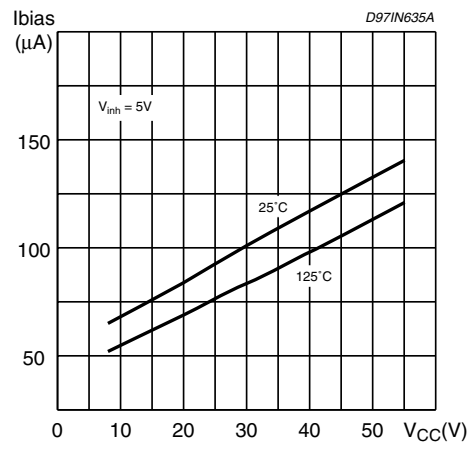


Figure 13. Reference Voltage vs. Junction Temperature (Pin 16)

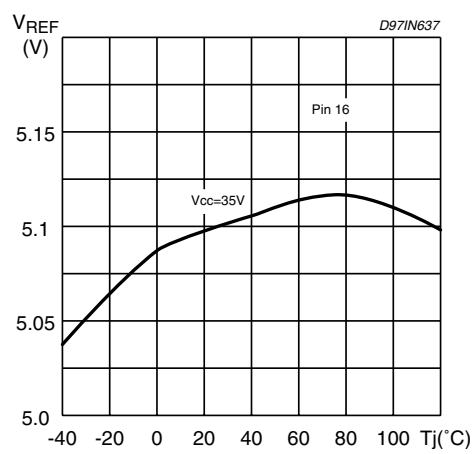


Figure 14. Reference Voltage vs. Input Voltage (Pin 16)

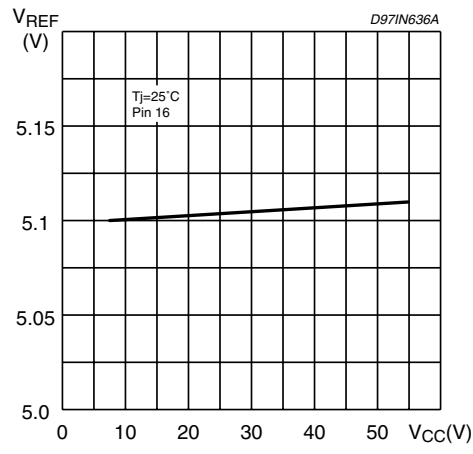


Figure 15. Reference Voltage vs. Reference Input Current

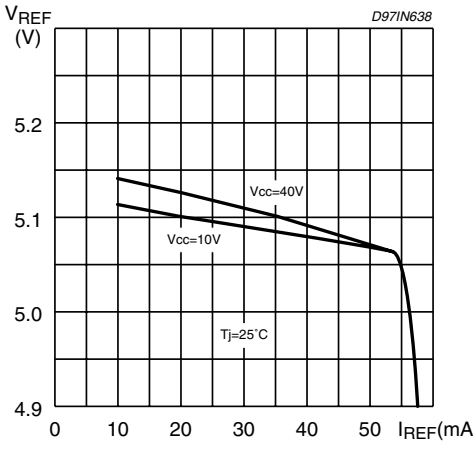


Figure 16. Inhibit Current vs. Inhibit Voltage (Pin 10)

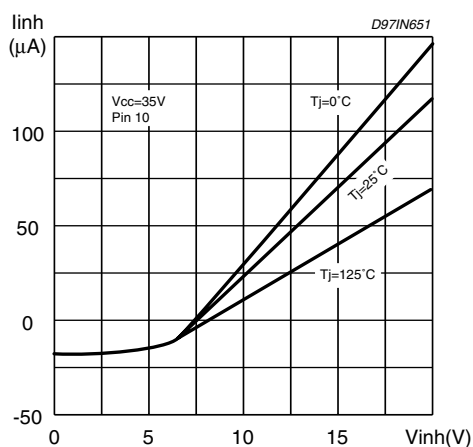


Figure 19. Line Regulation (see fig. 9)

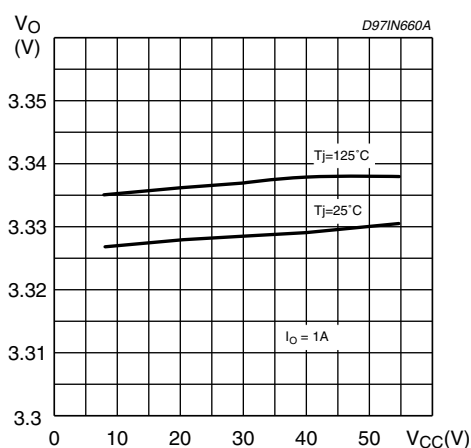


Figure 17. Line Regulation (see fig. 5)

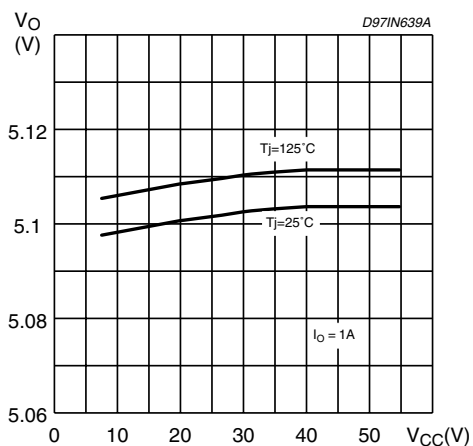


Figure 20. Load Regulation (see fig. 9)

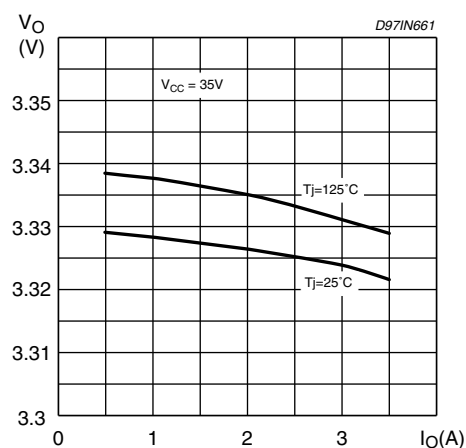


Figure 18. Load Regulation (see fig. 8)

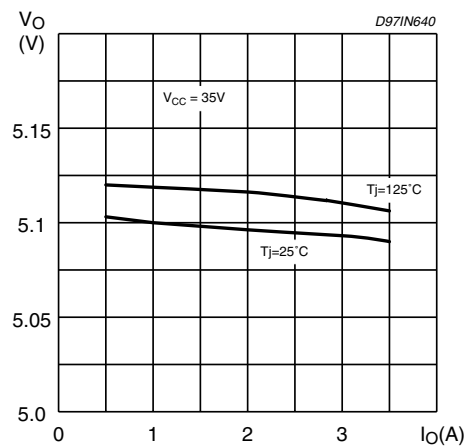


Figure 21. Switching Frequency vs. R2 and C7 (fig. 5)

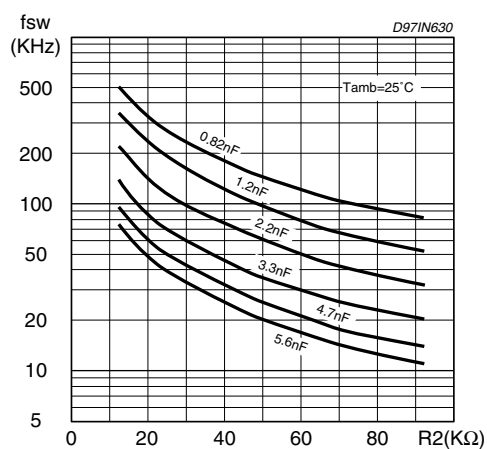


Figure 22. Switching Frequency vs. Input Voltage

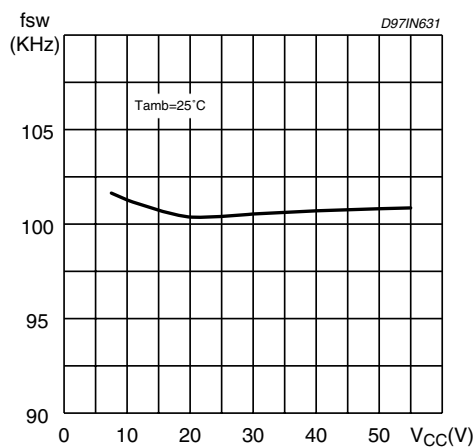


Figure 23. Switching Frequency vs. Junction temperature (see fig. 5)

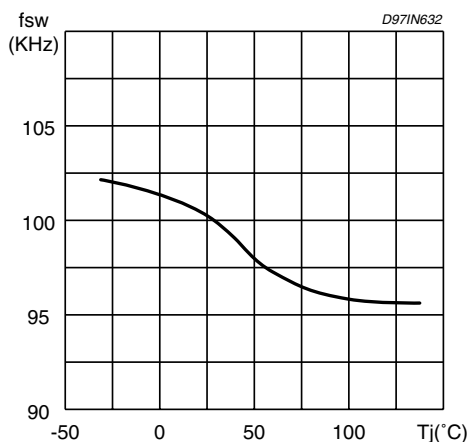


Figure 24. Dropout Voltage Between pin 7,8 and 2,3

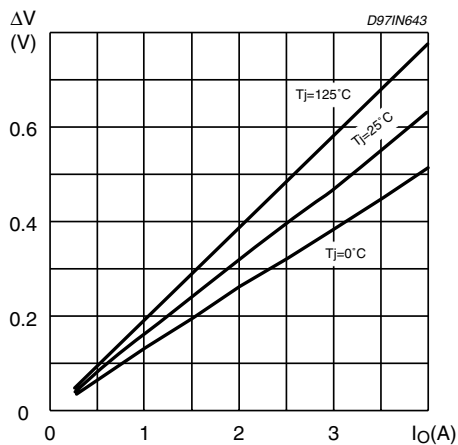


Figure 25. Efficiency vs. Output Voltage (see fig. 5)

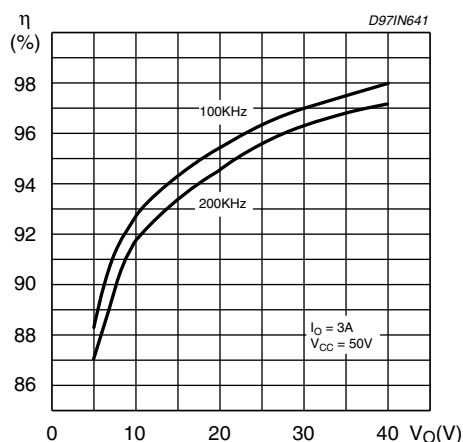


Figure 26. Efficiency vs. Output Voltage (Diode STPS745D)

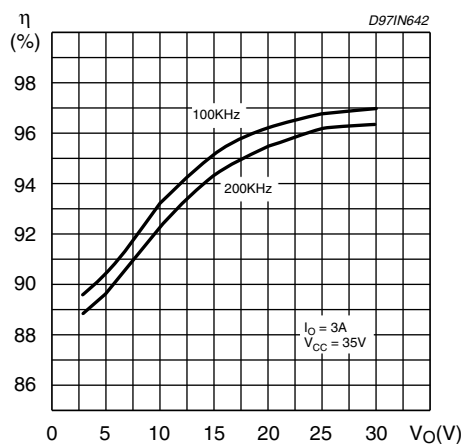


Figure 27. Efficiency vs. Output Current (see fig.8)

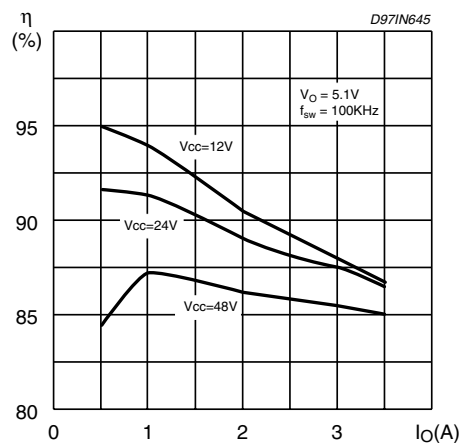


Figure 28. Efficiency vs. Output Current (see fig.8)

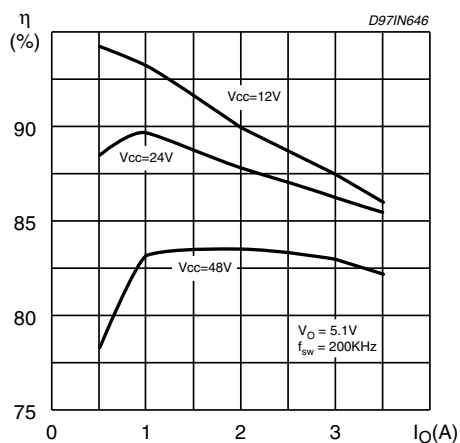


Figure 29. Efficiency vs. Output Current (see fig. 9)

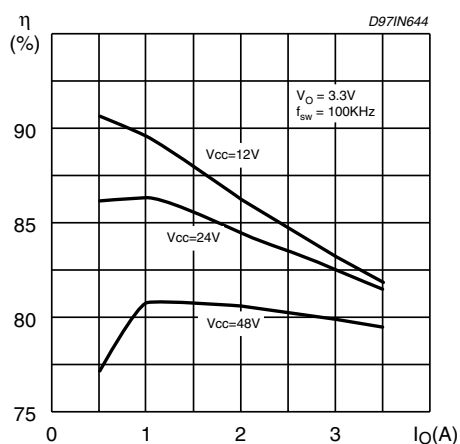


Figure 30. Efficiency vs. Output Current (see fig. 9)

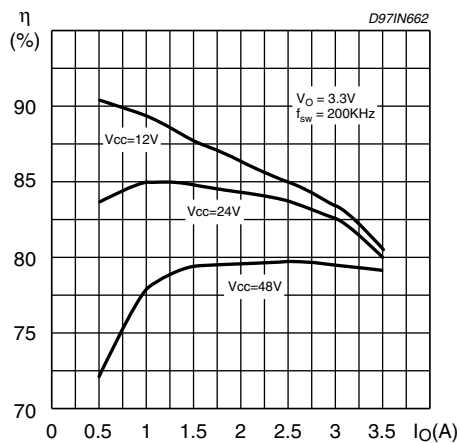


Figure 31. Power dissipation vs. Input Voltage (Device only) (see fig. 8)

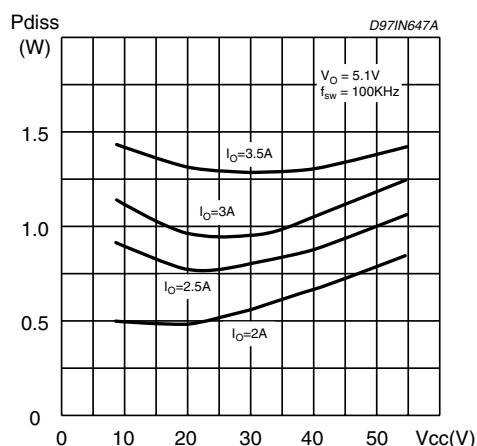


Figure 32. Power dissipation vs. Output Voltage (Device only)

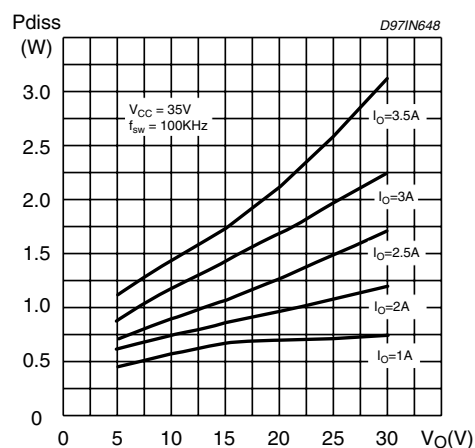


Figure 33. Pulse by Pulse Limiting Current vs. Junction Temperature

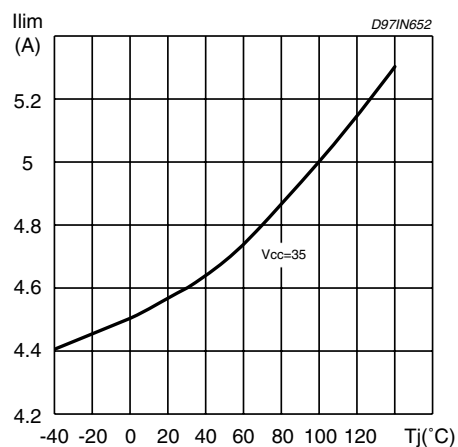


Figure 34. Load Transient

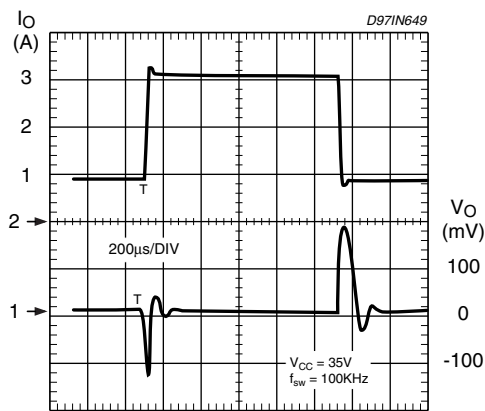


Figure 35. Line Transient

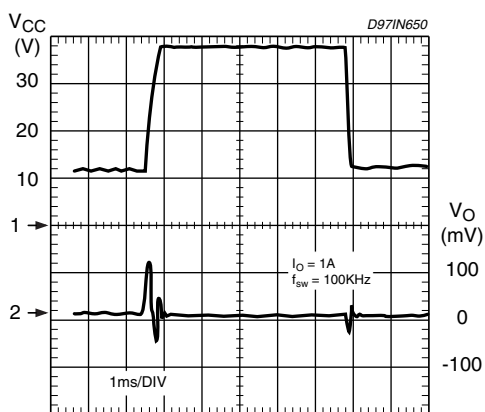


Figure 36. Source Current Rise and Fall Time, pin 2, 3 (See fig. 5)

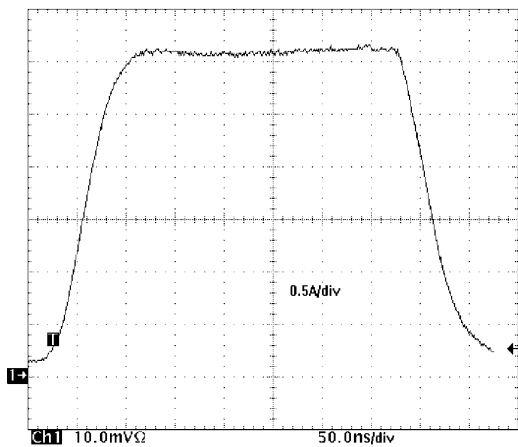


Figure 37. Soft Start Capacitor Selection vs. Inductor and V_{CC} max (ref. AN938)

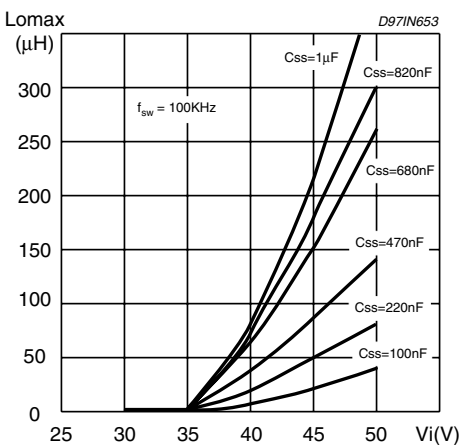


Figure 38. Soft Start Capacitor Selection vs. Inductor and V_{CC} max (ref. AN938)

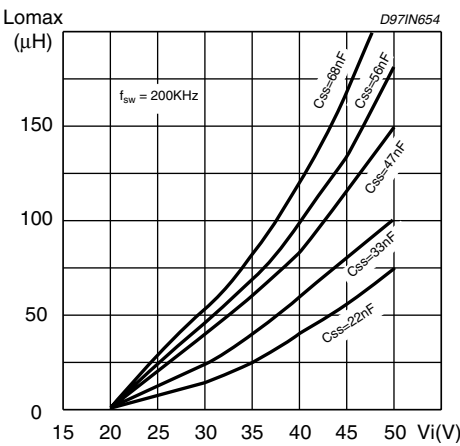


Figure 39. Open Loop Frequency and Phase of Error amplifier

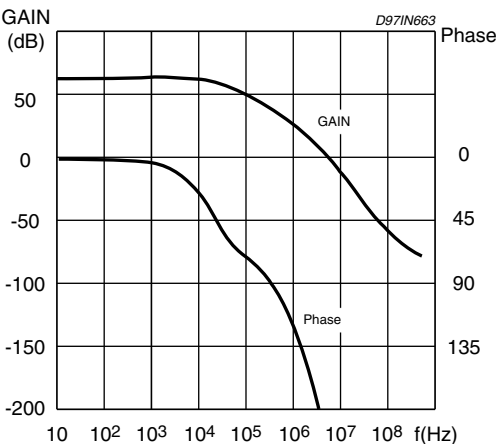


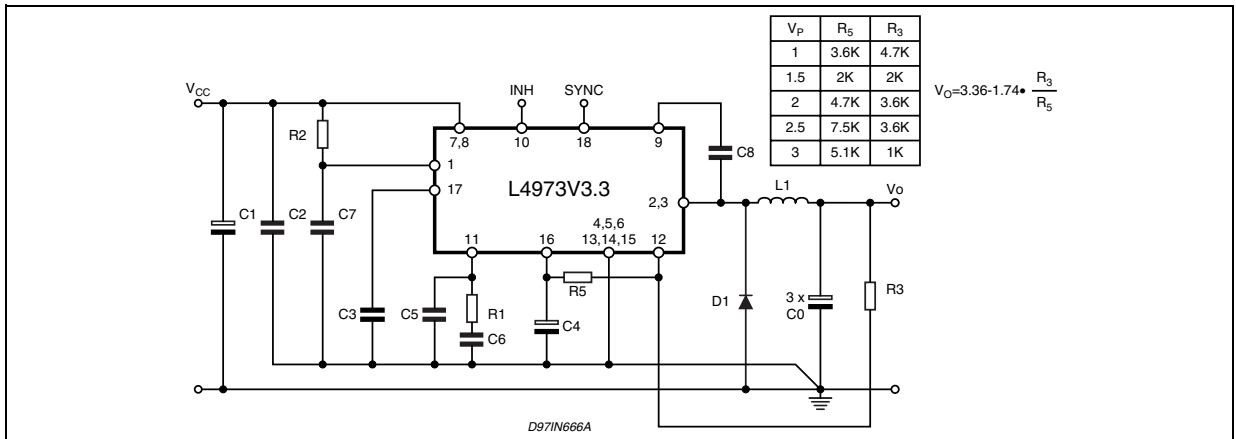
Figure 40. 3.5A at $V_O < 3.3V$ (see part list fig. 5)

Figure 41. 12V to 3.3V High Performance Buck Converter (fsw = 200kHz)

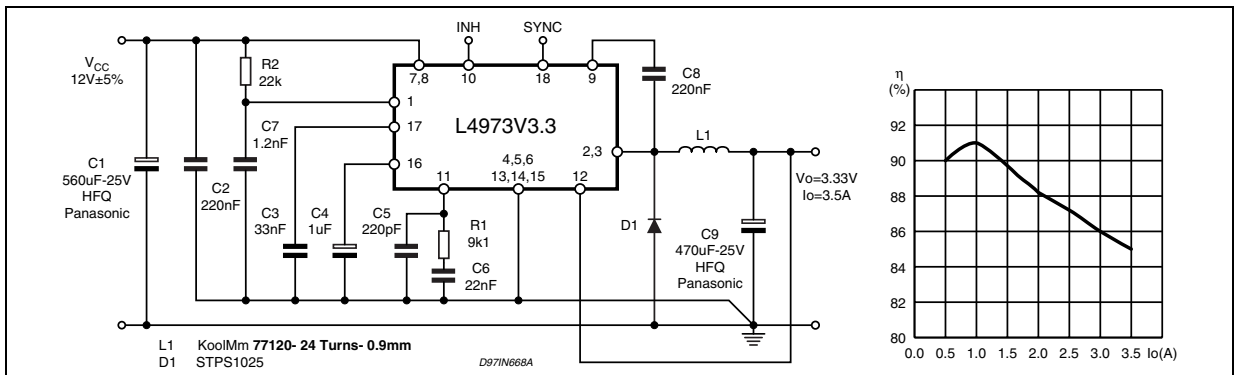


Figure 42. Synchronization Example

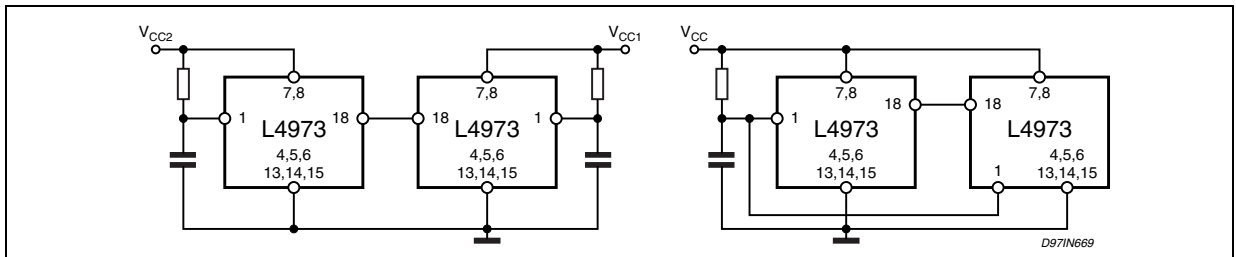
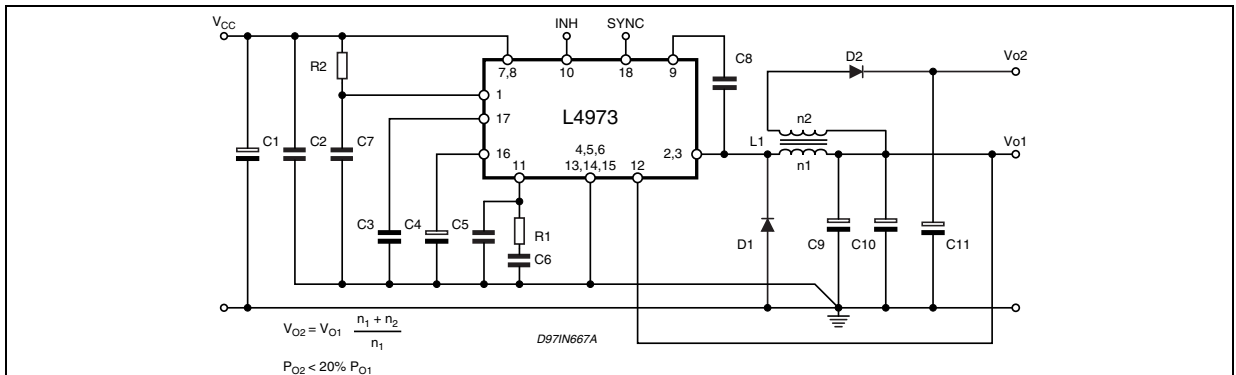


Figure 43. Multioutput not Isolated (Pin out referred to DIP12+3+3)

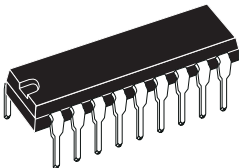


3 Package Information

Figure 44. Powerdip-18 Mechanical Data & Package Dimensions

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.85		1.40	0.033		0.055
b		0.50			0.020	
b1	0.38		0.50	0.015		0.020
D			24.80			0.976
E		8.80			0.346	
e		2.54			0.100	
e3		20.32			0.800	
F			7.10			0.280
I			5.10			0.201
L		3.30			0.130	
Z			2.54			0.100

OUTLINE AND
MECHANICAL DATA



Powerdip 18

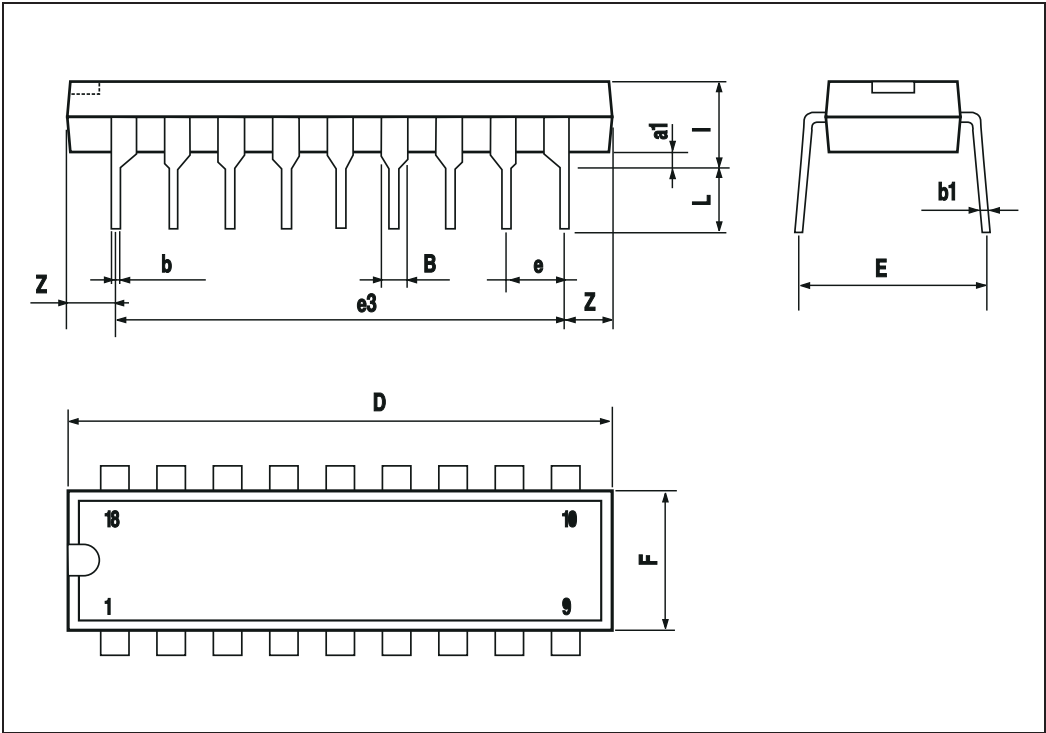
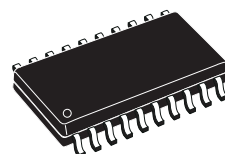


Figure 45. SO-20 Mechanical Data & Package Dimensions

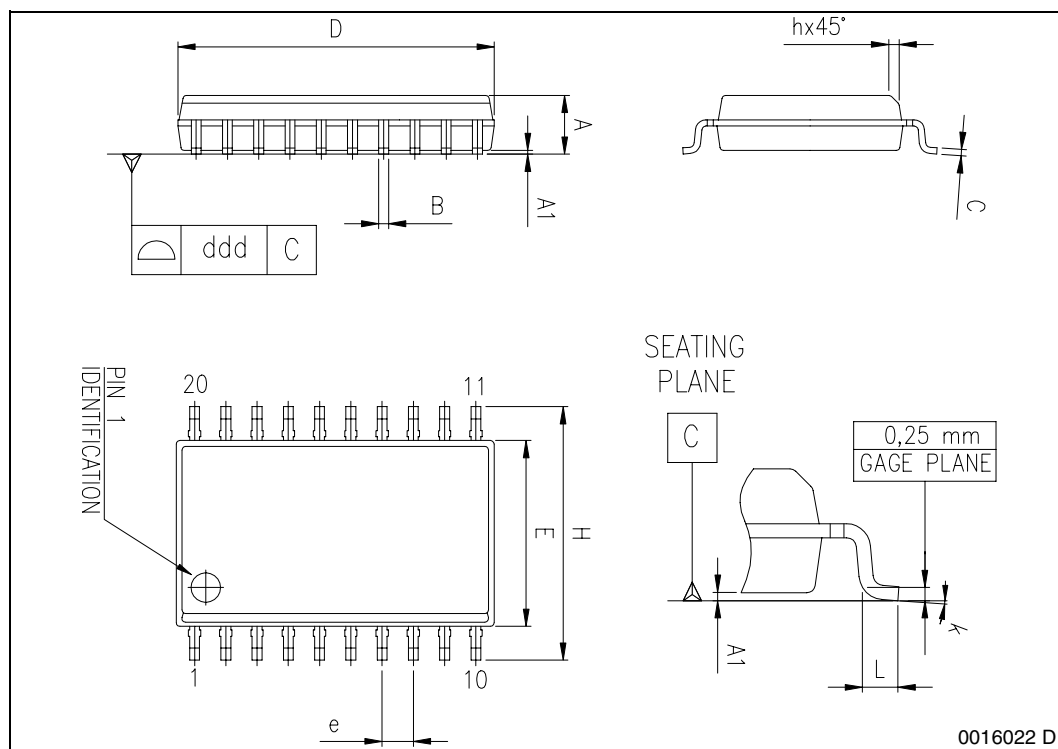
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.35		2.65	0.093		0.104
A1	0.10		0.30	0.004		0.012
B	0.33		0.51	0.013		0.200
C	0.23		0.32	0.009		0.013
D ⁽¹⁾	12.60		13.00	0.496		0.512
E	7.40		7.60	0.291		0.299
e		1.27			0.050	
H	10.0		10.65	0.394		0.419
h	0.25		0.75	0.010		0.030
L	0.40		1.27	0.016		0.050
k	0° (min.), 8° (max.)					
ddd			0.10			0.004

(1) "D" dimension does not include mold flash, protusions or gate burrs. Mold flash, protusions or gate burrs shall not exceed 0.15mm per side.

OUTLINE AND MECHANICAL DATA



SO20



4 Revision History

Table 7. Revision History

Date	Revision	Description of Changes
September 2001	13	First Issue
May 2005	14	Updated the Layout look & feel. Changed name of the D1 on the fig. 5.

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